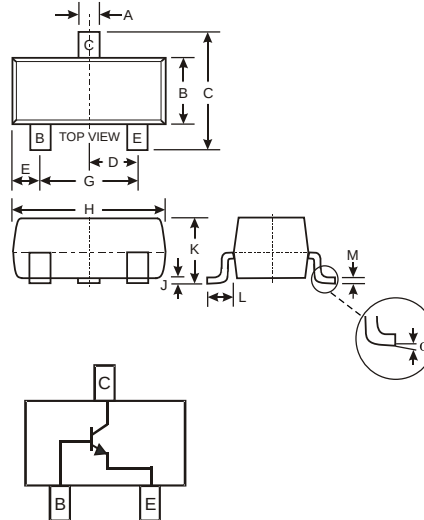


Features

- Σ Epitaxial Planar Die Construction
- Σ Complementary PNP Type Available (MMBT2907A)
- Σ Ideal for Medium Power Amplification and Switching
- Σ **Lead Free/RoHS Compliant (Note 2)**

Mechanical Data

- Σ Case: SOT-23
- Σ Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Σ Moisture Sensitivity: Level 1 per J-STD-020C
- Σ Terminals: Solderable per MIL-STD-202, Method 208
- Σ Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Σ Terminal Connections: See Diagram
- Σ Marking (See Page 2): K1P
- Σ Ordering & Date Code Information: See Page 4
- Σ Weight: 0.008 grams (approximate)



SOT-23		
Dim	Min	Max
A	0.37	0.51
B	1.20	1.40
C	2.30	2.50
D	0.89	1.03
E	0.45	0.60
G	1.78	2.05
H	2.80	3.00
J	0.013	0.10
K	0.903	1.10
L	0.45	0.61
M	0.085	0.180
a	0 ∞	8 ∞
All Dimensions in mm		

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	MMBT2222A	Unit
Collector-Base Voltage	V _{CBO}	75	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Collector Current - Continuous	I _C	600	mA
Peak Collector Current	I _{CM}	800	mA
Power Dissipation (Note 1)	P _d	300	mW
Thermal Resistance, Junction to Ambient (Note 1)	R _{qJA}	417	°C/W
Operating and Storage and Temperature Range	T _J , T _{STG}	-55 to +150	°C

- Notes:
1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
 2. No purposefully added lead.

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic (Note 3)	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS					
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	75	∞	V	$I_C = 10\text{mA}$, $I_E = 0$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	40	∞	V	$I_C = 10\text{mA}$, $I_B = 0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	6.0	∞	V	$I_E = 10\text{mA}$, $I_C = 0$
Collector Cutoff Current	I_{CBO}	∞	10	nA	$V_{CB} = 60\text{V}$, $I_E = 0$ $V_{CB} = 60\text{V}$, $I_E = 0$, $T_A = 150^\circ\text{C}$
Collector Cutoff Current	I_{CEX}	∞	10	nA	$V_{CE} = 60\text{V}$, $V_{EB(OFF)} = 3.0\text{V}$
Emitter Cutoff Current	I_{EBO}	∞	10	nA	$V_{EB} = 3.0\text{V}$, $I_C = 0$
Base Cutoff Current	I_{BL}	∞	20	nA	$V_{CE} = 60\text{V}$, $V_{EB(OFF)} = 3.0\text{V}$
ON CHARACTERISTICS					
DC Current Gain	h_{FE}	35 50 75 100 40 50 35	∞ ∞ ∞ 300 ∞ ∞ ∞	∞	$I_C = 100\text{mA}$, $V_{CE} = 10\text{V}$ $I_C = 1.0\text{mA}$, $V_{CE} = 10\text{V}$ $I_C = 10\text{mA}$, $V_{CE} = 10\text{V}$ $I_C = 150\text{mA}$, $V_{CE} = 10\text{V}$ $I_C = 500\text{mA}$, $V_{CE} = 10\text{V}$ $I_C = 10\text{mA}$, $V_{CE} = 10\text{V}$, $T_A = -55^\circ\text{C}$ $I_C = 150\text{mA}$, $V_{CE} = 1.0\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	∞	0.3 1.0	V	$I_C = 150\text{mA}$, $I_B = 15\text{mA}$ $I_C = 500\text{mA}$, $I_B = 50\text{mA}$
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	0.6 ∞	1.2 2.0	V	$I_C = 150\text{mA}$, $I_B = 15\text{mA}$ $I_C = 500\text{mA}$, $I_B = 50\text{mA}$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C_{obo}	∞	8	pF	$V_{CB} = 10\text{V}$, $f = 1.0\text{MHz}$, $I_E = 0$
Input Capacitance	C_{ibo}	—	25	pF	$V_{EB} = 0.5\text{V}$, $f = 1.0\text{MHz}$, $I_C = 0$
Current Gain-Bandwidth Product	f_T	300	∞	MHz	$V_{CE} = 20\text{V}$, $I_C = 20\text{mA}$, $f = 100\text{MHz}$
Noise Figure	NF	∞	4.0	dB	$V_{CE} = 10\text{V}$, $I_C = 100\text{mA}$, $R_S = 1.0\text{k}\Omega$, $f = 1.0\text{kHz}$
SWITCHING CHARACTERISTICS					
Delay Time	t_d	∞	10	ns	$V_{CC} = 30\text{V}$, $I_C = 150\text{mA}$, $V_{BE(off)} = -0.5\text{V}$, $I_{B1} = 15\text{mA}$
Rise Time	t_r	∞	25	ns	
Storage Time	t_s	∞	225	ns	$V_{CC} = 30\text{V}$, $I_C = 150\text{mA}$, $I_{B1} = I_{B2} = 15\text{mA}$
Fall Time	t_f	∞	60	ns	

Note: 3. Short duration test pulse used to minimize self-heating effect.

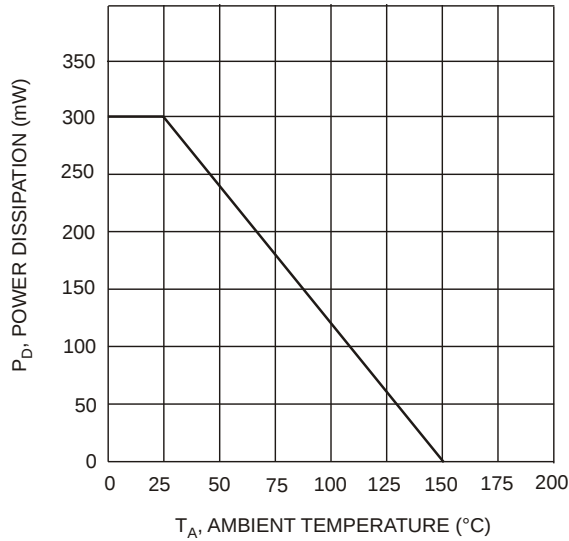


Fig. 1, Max Power Dissipation vs Ambient Temperature

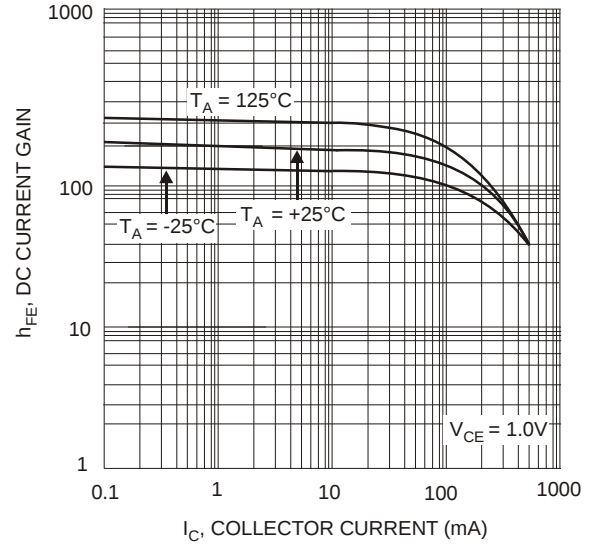


Fig. 2, Typical DC Current Gain vs Collector Current

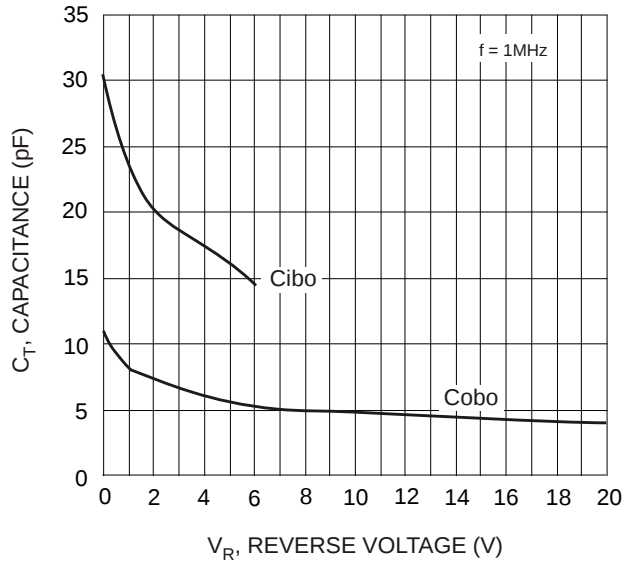


Fig. 3, Typical Capacitance Characteristics

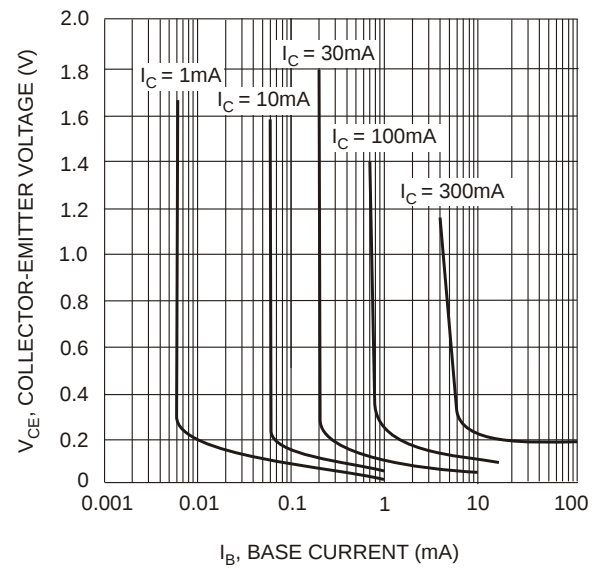


Fig. 4, Typical Collector Saturation Region

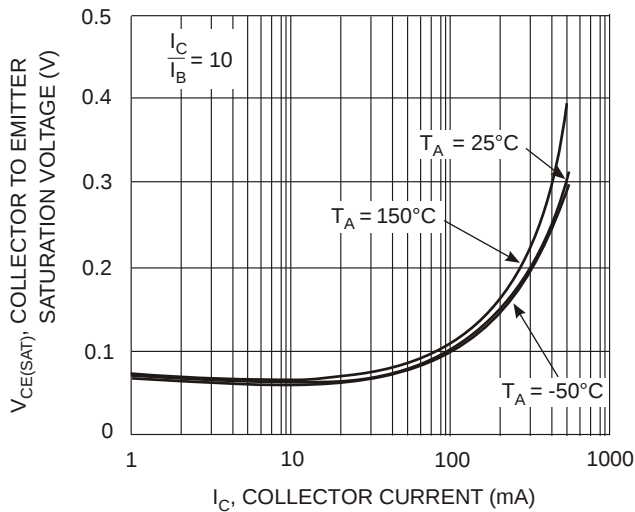


Fig. 5, Collector-Emitter Saturation Voltage vs. Collector Current

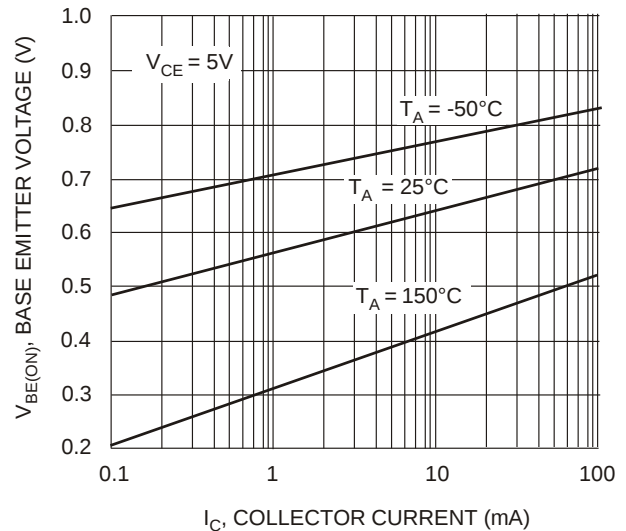


Fig. 6, Base-Emitter Voltage vs. Collector Current

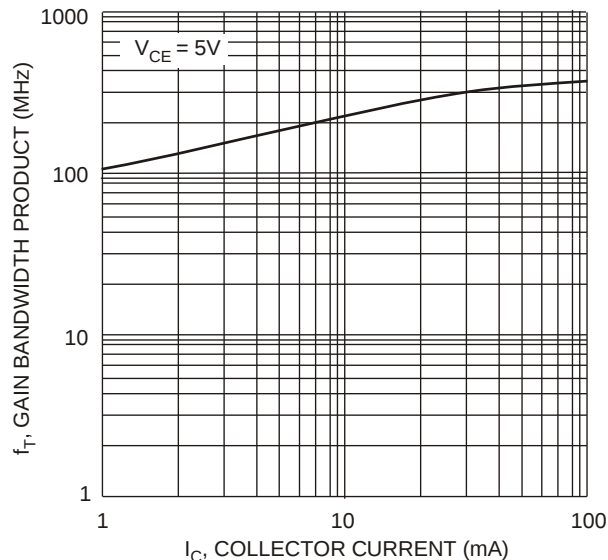


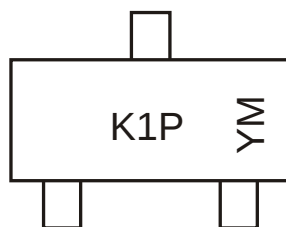
Fig. 7 Gain Bandwidth Product vs. Collector Current

Ordering Information (Note 4)

Device	Packaging	Shipping
MMBT2222A-7-F	SOT-23	3000/Tape & Reel

Note: 4. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



K1P = Product Type Marking Code
 YM = Date Code Marking
 Y = Year ex: N = 2002
 M = Month ex: 9 = September

Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009
Code	J	K	L	M	N	P	R	S	T	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

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